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Vishay Siliconix

Automotive N-Channel 20 V (D-S) 175 °C MOSFET

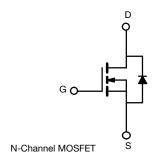
PRODUCT SUMMARY			
V _{DS} (V)	20		
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0035		
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$	0.0045		
I _D (A)	100		
Configuration	Single		
Package	TO-263		



- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>







ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V_{DS}	20	V	
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current	T _C = 25 °C a		100		
	T _C = 125 °C		80		
Continuous Source Current (Diode Conduction) a		I _S	100	Α	
Pulsed Drain Current ^b		I _{DM}	220		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	45		
Single Pulse Avalanche Energy	L = 0.1 MH	E _{AS}	101	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	D	150	10/	
	T _C = 125 °C	P_{D}	50	W	
Operating Junction and Storage Temperature Range		T _J , T _{sta}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient P	CB Mount c	R_{thJA}	40	°C/W	
Junction-to-Case (Drain)	o-Case (Drain)		1	C/VV	

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- c. When mounted on 1" square PCB (FR4 material).



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PARAMETER	SYMBOL	TES	TEST CONDITIONS		TYP.	MAX.	UNIT	
Static					•			
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		20	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$		1.5	2.0	2.5		
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA	
Zero Gate Voltage Drain Current		V _{GS} = 0 V	V _{DS} = 20 V	-	-	1		
	I _{DSS}	V _{GS} = 0 V	V _{DS} = 20 V, T _J = 125 °C	-	-	50	μA	
		V _{GS} = 0 V	V _{DS} = 20 V, T _J = 175 °C	-	-	250	μA	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	50	-	-	Α	
Drain-Source On-State Resistance ^a		V _{GS} = 10 V	I _D = 30 A	-	0.0020	0.0035	Ω	
		V _{GS} = 10 V	I _D = 30 A, T _J = 125 °C	-	-	0.0050		
	R _{DS(on)}	V _{GS} = 10 V	I _D = 30 A, T _J = 175 °C	-	-	0.0058		
		V _{GS} = 4.5 V	I _D = 20 A	-	0.0030	0.0045		
Forward Transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 30 A		-	186	-	S	
Dynamic b								
Input Capacitance	C _{iss}		V _{DS} = 10 V, f = 1 MHz	-	4300	5500	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$		-	1350	1700		
Reverse Transfer Capacitance	C _{rss}			-	585	800		
Total Gate Charge ^c	Qg		V _{DS} = 10 V, I _D = 50 A	-	70	110	nC	
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V		-	21	-		
Gate-Drain Charge ^c	Q _{gd}]		-	11	-		
Gate Resistance	R _g	f = 1 MHz		1.1	2.3	3.5	Ω	
Turn-On Delay Time ^c	t _{d(on)}			-	15	25		
Rise Time ^c	t _r	$V_{DD} = 10 \text{ V}, \text{ R}_{L} = 0.2 \Omega$ $I_{D} \cong 50 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_{g} = 1 \Omega$		-	5	10	- ns	
Turn-Off Delay Time c	t _{d(off)}			-	38	60		
Fall Time ^c	t _f			-	15	25		
Source-Drain Diode Ratings and Chara	acteristics ^b				<u> </u>			
Pulsed Current ^a	I _{SM}			-	-	220	Α	
Forward Voltage	V _{SD}	$I_F = 50 \text{ A}, V_{GS} = 0 \text{ V}$		-	0.86	1.5	V	

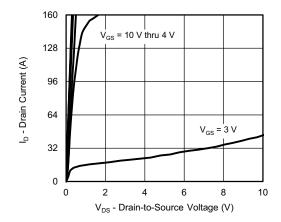
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

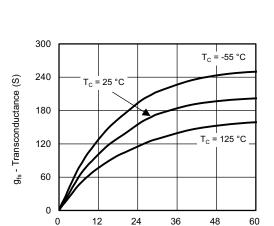
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

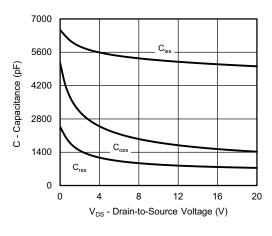


Output Characteristics

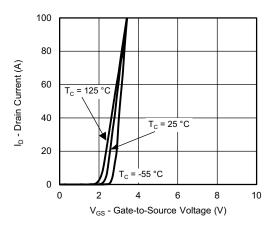


Transconductance

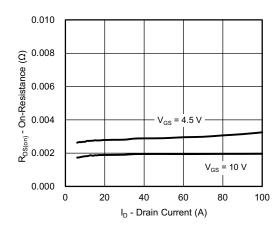
I_D - Drain Current (A)



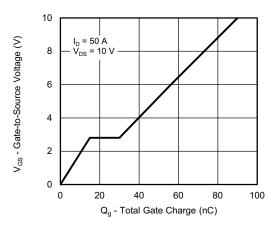
Capacitance



Transfer Characteristics



On-Resistance vs. Drain Current

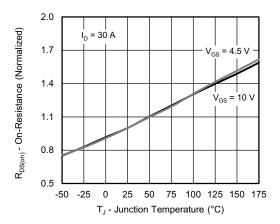


Gate Charge

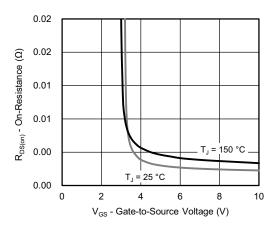
For technical questions, contact: automostechsu



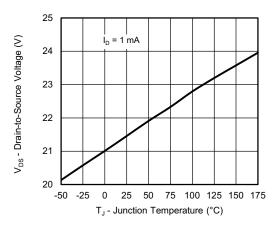
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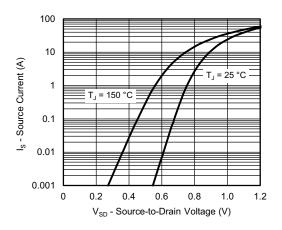
On-Resistance vs. Junction Temperature



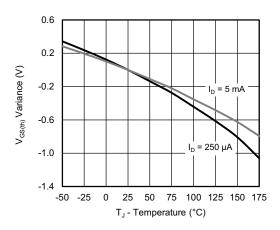
On-Resistance vs. Gate-to-Source Voltage



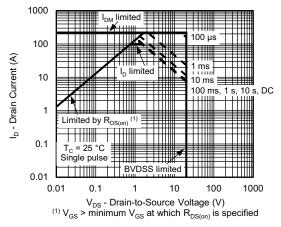
Drain Source Breakdown vs. Junction Temperature



Source Drain Diode Forward Voltage



Threshold Voltage

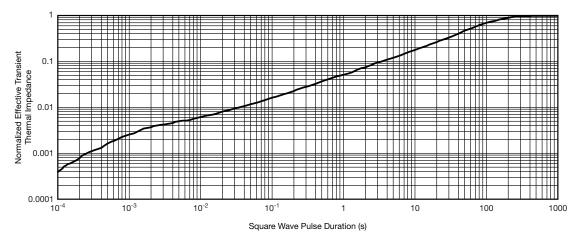


Safe Operating Area

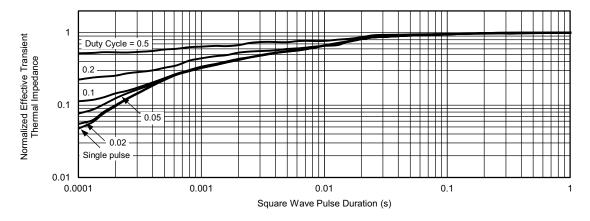
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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg276456.



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